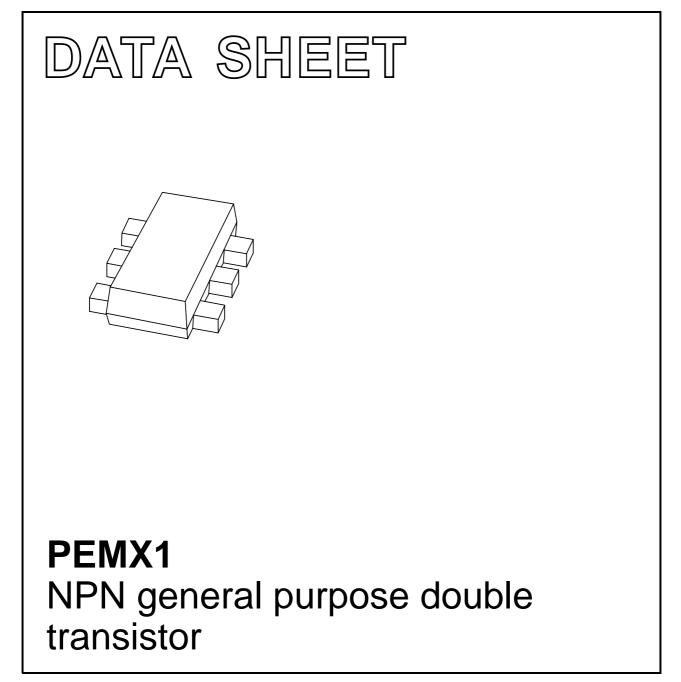
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2001 Aug 30 2001 Nov 07



FEATURES

- 300 mW total power dissipation
- Very small 1.6 mm x 1.2 mm ultra thin package
- Excellent coplanarity due to straight leads
- Replaces two SC-75/SC-89 packaged transistors on same PCB area
- Reduced required PCB area
- Reduced pick and place costs.

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

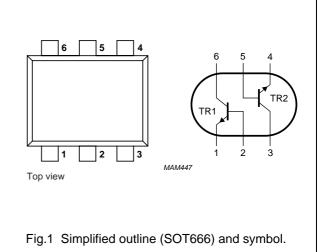
NPN double transistor pair in a SOT666 plastic package. PNP complement: PEMT1.

MARKING

TYPE NUMBER	MARKING CODE		
PEMX1	ZZ		

PINNING

PIN	DESCRIPTION		
1, 4	emitter	TR1; TR2	
2, 5	base	TR1; TR2	
6, 3	collector	TR1; TR2	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transi	stor				
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	40	V
V _{EBO}	emitter-base voltage	open collector	_	5	V
I _C	collector current (DC)		-	100	mA
I _{CM}	peak collector current		_	200	mA
I _{BM}	peak base current		_	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C; note 1$	-	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C
Per device	9	*			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW

Note

1. Transistor mounted on an FR4 printed-circuit board.

PEMX1

PEMX1

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

Notes

- 1. Transistor mounted on an FR4 printed-circuit board.
- 2. The only recommended soldering is reflow soldering.

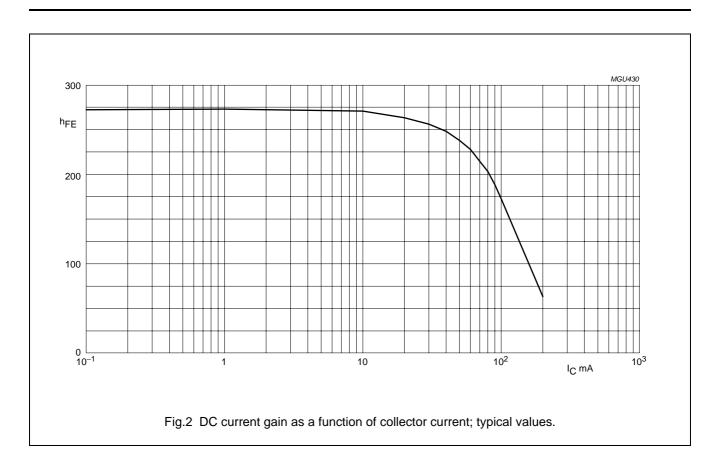
CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transis	Per transistor				
I _{CBO}	collector-base cut-off current	$V_{CB} = 30 \text{ V}; \text{ I}_{E} = 0$	-	100	nA
		$V_{CB} = 30 \text{ V}; \text{ I}_{E} = 0; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	10	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 4 V; I_{C} = 0$	-	100	nA
h _{FE}	DC current gain	V _{CE} = 6 V; I _C = 1 mA	120	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 50 \text{ mA}; I_{B} = 5 \text{ mA}; \text{ note } 1$	-	200	mV
Cc	collector capacitance	$V_{CB} = 12 \text{ V}; \text{ I}_{E} = \text{ I}_{e} = 0; \text{ f} = 1 \text{ MHz}$	-	1.5	pF
f _T	transition frequency	I _C = 2 mA; V _{CE} = 12 V; f = 100 MHz	100	-	MHz

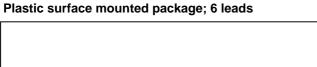
Note

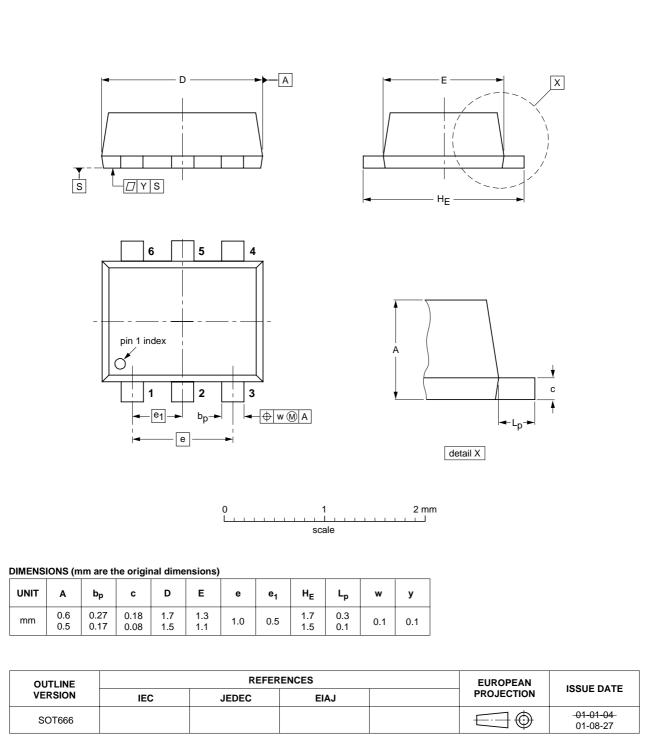
1. Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



PEMX1

PACKAGE OUTLINE





Product data sheet

PEMX1

SOT666

PEMX1

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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